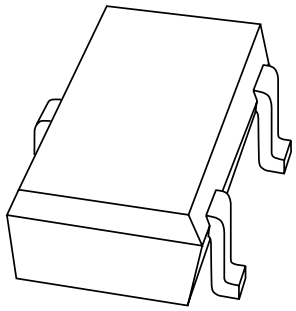
DATA SHEET



PMST2907A
PNP switching transistor

Product specification
Supersedes data of 1999 Apr 22

2001 Nov 19

Philips
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PNP switching transistor PMST2907A

FEATURES

- Low current (max. 600 mA)
- Low voltage (max. 60 V).

APPLICATIONS

- Medium power switching
- General purpose amplification.

DESCRIPTION

PNP switching transistor in an SC-70; SOT323 plastic package. NPN complement: PMST2222A.

MARKING

TYPE NUMBER	MARKING CODE(1)
PMST2907A	∗2F

Note

1. ∗ = - : Made in Hong Kong.
   ∗ = t : Made in Malaysia.

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector

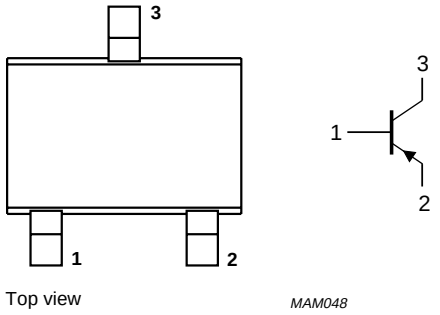


Fig.1 Simplified outline (SC-70; SOT323) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	–60	V
V_{CEO}	collector-emitter voltage	open base	–	–60	V
V_{EBO}	emitter-base voltage	open collector	–	–5	V
I_C	collector current (DC)		–	–600	mA
I_{CM}	peak collector current		–	–800	mA
I_{BM}	peak base current		–	–200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C; note 1	–	200	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	note 1	625	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

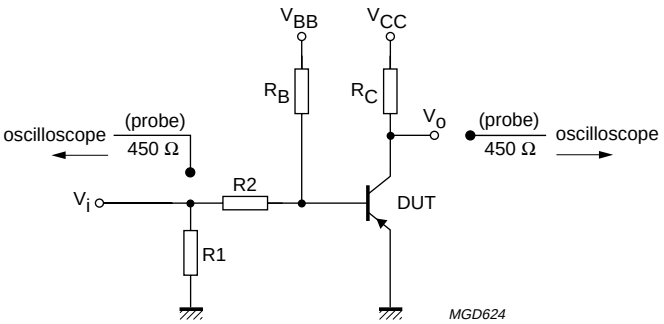
CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{CBO}	collector cut-off current	I_E = 0; V_{CB} = –50 V	–	–10	nA
		I_E = 0; V_{CB} = –50 V; T_j = 150 °C	–	–10	µA
I_{EBO}	emitter cut-off current	I_C = 0; V_{EB} = –3 V	–	–50	nA
h_{FE}	DC current gain	V_{CE} = –10 V			
		I_C = –0.1 mA	75	–	
		I_C = –1 mA	100	–	
		I_C = –10 mA; note 1	100	–	
		I_C = –150 mA; note 1	100	300	
		I_C = –500 mA; note 1	50	–	
V_{CEsat}	collector-emitter saturation voltage	I_C = –150 mA; I_B = –15 mA; note 1	–	–400	mV
		I_C = –500 mA; I_B = –50 mA; note 1	–	–1.6	V
V_{BEsat}	base-emitter saturation voltage	I_C = –150 mA; I_B = –15 mA; note 1	–	–1.3	V
		I_C = –500 mA; I_B = –50 mA; note 1	–	–2.6	V
C_c	collector capacitance	$I_E = i_e$ = 0; V_{CB} = –10 V; f = 1 MHz	–	8	pF
C_e	emitter capacitance	$I_C = i_c$ = 0; V_{EB} = –2 V; f = 1 MHz	–	30	pF
f_T	transition frequency	I_C = –50 mA; V_{CE} = –20 V; f = 100 MHz; note 1	200	–	MHz
Switching times (between 10% and 90% levels); (see Fig.2)					
t_{on}	turn-on time	I_{Con} = –150 mA; I_{Bon} = –15 mA; I_{Boff} = 15 mA	–	45	ns
t_d	delay time		–	15	ns
t_r	rise time		–	35	ns
t_{off}	turn-off time		–	300	ns
t_s	storage time		–	250	ns
t_f	fall time		–	50	ns

Note

1. Pulse test: $t_p \leq 300$ µs; $\delta \leq 0.02$.

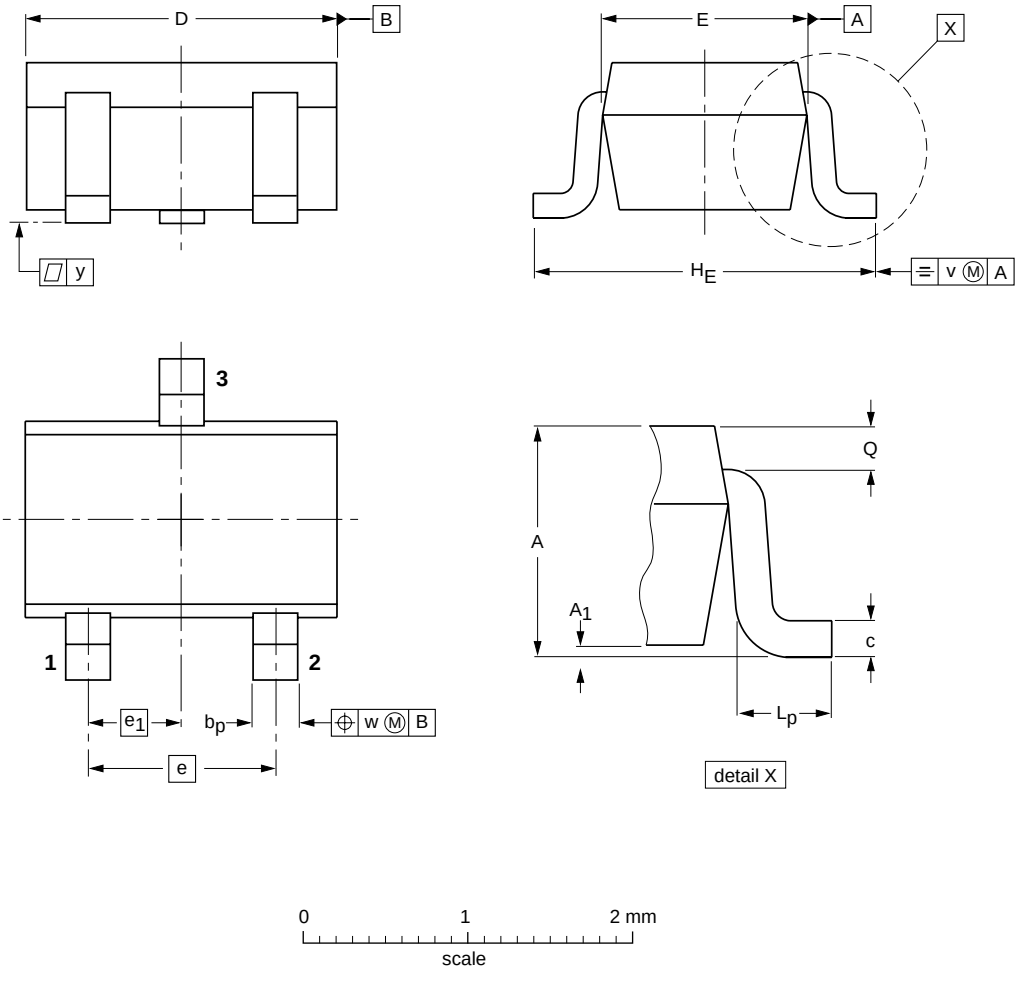


V_i = –9.5 V; T = 500 µs; t_p = 10 µs; $t_r = t_f \leq 3$ ns.
R1 = 68 Ω; R2 = 325 Ω; R_B = 325 Ω; R_C = 160 Ω.
V_{BB} = 3.5 V; V_{CC} = –29.5 V.
Oscilloscope input impedance Z_i = 50 Ω.

Fig.2 Test circuit for switching times.

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads **SOT323**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1 max	b_p	c	D	E	e	e_1	H_E	L_p	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT323			SC-70			97-02-28

DATA SHEET STATUS

DATA SHEET STATUS[1]	PRODUCT STATUS[2]	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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Contact information

For additional information please visit **http://www.semiconductors.philips.com**. Fax: **+31 40 27 24825**
For sales offices addresses send e-mail to: **sales.addresses@www.semiconductors.philips.com**.

Printed in The Netherlands 613514/03/pp8 Date of release: 2001 Nov 19 Document order number: 9397 750 09002

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